PATENT COOPERATION TREATY

From the INTERNATIONAL SEARCHING AUTHORITY		•			
To: Atsushi AOKI		PCT			
A. AOKI, ISHIDA & ASSOCIATES, Toranomon 37 Mori Bldg., 5-1, Tranomon 3-chome, Minato-ku,		ITTEN OPINION OF THE ONAL SEARCHING AUTHORIT	ГΥ		
Tokyo 1058423 Japan		(PCT Rule 43bis.1)			
	Date of mailing (day/month/year)	22 02 0005			
Applicant's or agent's file reference P931-PCT	FOR FURTHER A	CTION 03.2005 See paragraph 2 below			
International application No. PCT/JP2004/019284 International filing date 16.12		Priority date (day/month/year) 17.12.2003			
International Patent Classification (IPC) or both national classificat	cation and IPC				
Applicant SHOWA DENKO K.K.					
1. This opinion contains indications relating to the following ite	ems:				
Box No. I Basis of the opinion	·				
Box No. II Priority					
Box No. III Non-establishment of opinion with regard to novelty, inventive step and industrial applicability					
Box No. IV Lack of unity of invention	·				
Box No. V Reasoned statement under Rule 43bis.1(a)(i) with regard to novelty, inventive step or industrial applicability citations and explanations supporting such statement					
Box No. VI Certain documents cited					
Box No. VII Certain defects in the international application					
Box No. VIII Certain observations on the international application					
2. FURTHER ACTION					
If a demand for international preliminary examination is ma International Preliminary Examining Authority ("IPEA") exce other than this one to be the IPEA and the chosen IPEA has n opinions of this International Searching Authority will not b	pt that this does not appoint that this does not appoint the international state of the control	ly where the applicant chooses an Auth	hority		
If this opinion is, as provided above, considered to be a written a written reply together, where appropriate, with amendments, PCT/ISA/220 or before the expiration of 22 months from the provided above.	before the expiration of	3 months from the date of mailing of 1	PEA Form		
For further options, see Form PCT/ISA/220.		•			
3. For further details, see notes to Form PCT/ISA/220.					
Date of completion of this opinion 09.03	.2005				
Name and mailing address of the ISA/JP	Authorized officer	4M 91	71		
Japan Patent Office	Ken HASEY				
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Form PCT/ISA/237 (cover sheet) (January 2004)

WRITTEN OPINION OF THE INTERNATIONAL SEARCHING AUTHORITY

International application No.

PCT/JP2004/019284

Вох	No. I	Basis of the opinion
1.	which	regard to the language, this opinion has been established on the basis of the international application in the language in it was filed, unless otherwise indicated under this item. This opinion has been established on the basis of a translation from the original language into the following language
		, which is the language of a translation furnished for the purposes of international search (under
		Rules 12.3 and 23.1(b)).
2.		regard to any nucleotide and/or amino acid sequence disclosed in the international application and necessary to the d invention, this opinion has been established on the basis of:
	a. type	e of material .
		a sequence listing
		table(s) related to the sequence listing
	b. form	mat of material
		in written format
		in computer readable form
	c. time	e of filing/furnishing
		contained in the international application as filed.
		filed together with the international application in computer readable form.
		furnished subsequently to this Authority for the purposes of search.
3.		In addition, in the case that more than one version or copy of a sequence listing and/or table relating thereto has been filed or furnished, the required statements that the information in the subsequent or additional copies is identical to that in the application as filed or does not go beyond the application as filed, as appropriate, were furnished.
4.	Addi	tional comments:
		•
		•
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AP3 Rec'd PCI/PIO 14 JUN 2008

WRITTEN OPINION OF THE INTERNATIONAL SEARCHING AUTHORITY

International application No. PCT/JP2004/019284

Box No. V Reasoned statement under Rule 43bis.1(a)(i) with regard to novelty, inventive step or industrial applicability; citations and explanations supporting such statement

Novelty (N)	Claims 1-	25	YE
	Claims		NC
Inventive step (IS)	Claims		
	Claims 1-	25	NC
Industrial applicability (IA)	Claims 1-	25	
	Claims		NC NC

2. Citations and explanations

The following documents cited in the international search report (ISR) have been considered for the purpose of this report.

D1= JP 2003-110140 A (Nichia Corporation) 2003.04.11, Paragraphs [0013], [0015], [0022], [0027], [0028], Figure 2 (Family: None)

D2= JP 2002-368271 A (Toyoda Gosei Co., Ltd.) 2002.12.20, Paragraphs [0011]-[0013], Figure 1 & EP 1406313 A1 & WO 2002/101841 A1

D3= JP 2003-224298 A (Nichia Corporation) 2003.08.08, Paragraphs [0010], [0023] (Family: None)

D4= JP 5-291621 A (Nichia Corporation) 1993.11.05, Paragraph [0009] (Family: None)

D5= US 2003/0194826 A1 (Toyoda Gosei Co., Ltd.) 2003.10.16, Paragraph [0040] & JP 2003-309285 A

Claims 1, 5-9, 14, 17, 19-25

The subject matters of claims 1, 5, 6, 7-9, 14, 17, 19-25 do not appear to involve an inventive step with respect to document D1. Since Cr or combination of some elements including Cr and Al as a material of negative alloy electrode of a GaN based compound semiconductor light-emitting device are shown in D1, it would be obvious for a person skilled in the art to determine a metallic elements to be included in the negative alloy electrode disclosed in D1 through experimentation as appropriate.

Claims 1, 5-8, 14-16, 23-25

The subject matters of claims 1, 5-8, 14-16, 23-25 do not appear to involve an inventive step with respect to document D2. Since Cr or combination of some elements including Cr and Al as a material of negative alloy electrode of a GaN based compound semiconductor light-emitting device are shown in D2, it would be obvious for a person skilled in the art to determine a metallic elements to be included in the negative alloy electrode disclosed in D2 through experimentation as appropriate.

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Supplemental Box

AP3 RAC' OPCT/PTO 14 JUN 2008

In case the space in any of the preceding boxes is not sufficient. Continuation of: V. 2

Claims 2-4

The subject matters of claims 2-4 do not appear to involve an inventive step with respect to document D1 or D2. It would be obvious for a person skilled in the art to optimize the rate of content of the negative alloy electrode disclosed in D1 or D2 through experimentation as appropriate.

Claims 10-13

The subject matters of claims 10-13 do not appear to involve an inventive step with respect to document D1 or D2, and the general knowledge of a person skilled in the art. It would be obvious for a person skilled in the art to conceive the idea of applying the provision of solder to the invention disclosed in D1 or D2.

Claims 15, 16

The subject matters of claims 15 and 16 do not appear to involve an inventive step with respect to a combination of documents D1 and D2. D2 discloses an adhesion layer formed of Ti, Cr or V with thickness of 10nm. Therefore it would be obvious for a person skilled in the art to conceive the idea of applying the technical features employed in D2 to the invention disclosed in D1.

Claims 17-22

The subject matters of claims 17-22 do not appear to involve an inventive step with respect to a combination of documents D1 and D2. D1 discloses a barrier layer formed of W, Ti or Ni with thickness of 200nm. Therefore it would be obvious for a person skilled in the art to conceive the idea of applying the technical features employed in D1 to the invention disclosed in D2.

Claims 1-25

The subject matters of claims 1-25 do not appear to involve an inventive step with respect to a combination of documents D1-D5 and the general knowledge of a person skilled in the art. D3-D5 disclose a metal including Cr and Al, or an alloy of any two or more kinds of metals selected from these metals, or a multi-layer structure thereof to be used as a material of negative alloy electrode of a GaN based compound semiconductor light-emitting device. Therefore it would be obvious for a person skilled in the art to conceive the idea of applying the technical features employed in D3-D5 to the invention disclosed in D1 or D2.